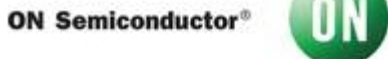
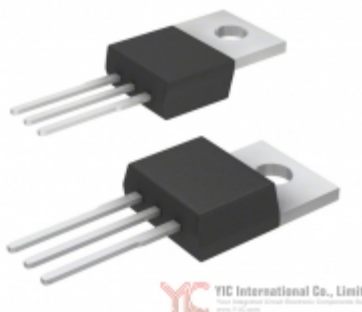



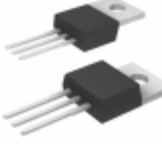



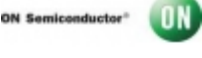



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|---|---|
|  | <p>NTP5864NG</p> |
| | <p>Hersteller-Teilenummer: NTP5864NG</p> |
|  | <p>Hersteller / Marke: AMI Semiconductor / ON Semiconductor</p> |
| | <p>Teil der Beschreibung: MOSFET N-CH 60V 63A TO-220</p> |
| | <p>Datenblätter:  NTP5864NG.pdf</p> |
| | <p>RoHs Status: Bleifrei / RoHS-konform</p> |
| | <p>Lagerzustand: New original, 92626 pcs Stock Available.</p> |
| | <p>Liefern von: Hong Kong</p> |
| <p>Image may be representation. See specs for product details.</p> | <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |

Spezifikationen

| | |
|--|--|
| Teilenummer | NTP5864NG |
| Hersteller | AMI Semiconductor / ON Semiconductor |
| Beschreibung | MOSFET N-CH 60V 63A TO-220 |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 92626 pcs Stock |
| Serie | - |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 175°C (TJ) |
| Befestigungsart | Through Hole |
| Verpackung / Gehäuse | TO-220-3 |
| Supplier Device-Gehäuse | TO-220AB |
| Verlustleistung (max) | 107W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 60V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 63A (Tc) |
| Rds On (Max) @ Id, Vgs | 12.4 mOhm @ 20A, 10V |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 31nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 1680pF @ 25V |
| Antriebsspannung (Max Rds On, Min Rds On) | 10V |
| Vgs (Max) | ±20V |
| Verpackung | Tube |




NTP5864NG ist neu im Original, Suche NTP5864NG Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie NTP5864NG AMI Semiconductor / ON Semiconductor mit Garantie und Vertrauen. Anfrage NTP5864NG: Info@Y-IC.com

Sie können auch interessiert sein:

| | | | |
|---|--|--|---|
|  <p>NTP60N06LG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A TO220AB</p> |  <p>NTP60N06G AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A TO220AB</p> |  <p>NTP6410AN ON NTP6410AN ON</p> |  <p>NTP5863N VB NTP5863N VB</p> |
|  <p>NTP5864N AMI Semiconductor / ON Semiconductor NTP5864N ON</p> |  <p>NTP60N06L AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 60A TO220AB</p> |  <p>NTP5863NG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V 97A TO-220AB</p> |  <p>NTP5862NG AMI Semiconductor / ON Semiconductor MOSFET N-CH 60V TO-220-3</p> |

heiße Teile

Mehr

| | | | | |
|--|---|--|---|---|
|  NTP30N20G |  NTP35N15 |  NTP35N15G |  NTP4302G |  NTP45N06 |
|  NTP45N06G |  NTP45N06L |  NTP45N06LG |  NTP477M04TDR |  NTP52N10 |
|  NTP52N10G |  NTP5404N |  NTP5404NRG |  NTP5411NG |  NTP5412NG |
|  NTP5426N |  NTP5426NG |  NTP5860N |  NTP5860NG |  NTP5860NL |
|  NTP5860NLG |  NTP5862NG |  NTP5863N |  NTP5863NG |  NTP5864N |
|  NTP60N06 |  NTP60N06G |  NTP60N06L |  NTP60N06LG |  NTP6410AN |
|  NTP6410ANG |  NTP6411AN |  NTP6411ANG |  NTP6412AN |  NTP6412ANG |
|  NTP6413AN |  NTP6413ANG |  NTP6448ANG |  NTP65N02R |  NTP65N02RG |
|  NTP75N03-006 |  NTP75N03-06 |  NTP75N03-06G |  NTP75N03-6G |  NTP75N03L09 |
|  NTP75N03L09G |  NTP75N03R |  NTP75N03RG |  NTP75N06 |  NTP75N06D |

Contact us: Info@Y-IC.com

HINZUFÜGEN: Einheit A5-B5 Nr.509, 5 / F Sing Win Fabrikgebäude, 15-17 Shing Yip St, Kwun Tong, Kowloon, HongKong.

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